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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/601,958	06/23/2003	Chun-Yi Yang	MXIC-P910252	8883
75	90 03/25/2004		EXAMINER	
Kenton R. Mullins			HA, NATHAN W	
Stout, Uxa, Buy	an & Mullins, LLP			
Suite 300			ART UNIT	PAPER NUMBER
4 Venture			2814	
Irvine, CA 92618			DATE MAIL ED: 03/25/2007	1

Please find below and/or attached an Office communication concerning this application or proceeding.

			<b>~</b>				
	Application No.	Applicant(s)					
	10/601,958	YANG, CHUN-YI					
Office Action Summary	Examiner	Art Unit					
	Nathan W. Ha	2814					
The MAILING DATE of this communicatio Period for Reply	n appears on the cover sheet w	vith the correspondence address					
A SHORTENED STATUTORY PERIOD FOR R THE MAILING DATE OF THIS COMMUNICATI  - Extensions of time may be available under the provisions of 37 C after SIX (6) MONTHS from the mailing date of this communication  - If the period for reply specified above is less than thirty (30) days  - If NO period for reply is specified above, the maximum statutory in  - Failure to reply within the set or extended period for reply will, by Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b).	ON.  FR 1.136(a). In no event, however, may a con.  , a reply within the statutory minimum of the period will apply and will expire SIX (6) MC statute, cause the application to become A	reply be timely filed irty (30) days will be considered timely. NTHS from the mailing date of this communi NBANDONED (35 U.S.C. § 133).	ication.				
Status							
1) Responsive to communication(s) filed on	23 December 2003.						
	This action is non-final.						
3) Since this application is in condition for al	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
4) ⊠ Claim(s) <u>1-30</u> is/are pending in the applic 4a) Of the above claim(s) <u>20-30</u> is/are with 5) ☐ Claim(s) is/are allowed. 6) ⊠ Claim(s) <u>1-16</u> is/are rejected. 7) ⊠ Claim(s) <u>17-19</u> is/are objected to. 8) ☐ Claim(s) are subject to restriction a	ndrawn from consideration.						
Application Papers							
9) The specification is objected to by the Exa 10) The drawing(s) filed on is/are: a) Applicant may not request that any objection to Replacement drawing sheet(s) including the co 11) The oath or declaration is objected to by the	accepted or b) objected to the drawing(s) be held in abeyon correction is required if the drawing	ance. See 37 CFR 1.85(a). g(s) is objected to. See 37 CFR 1.1					
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for for a) All b) Some * c) None of:  1. Certified copies of the priority docu 2. Certified copies of the priority docu 3. Copies of the certified copies of the application from the International B  * See the attached detailed Office action for	ments have been received. ments have been received in e priority documents have bee sureau (PCT Rule 17.2(a)).	Application No n received in this National Stag	e				
Attachment(s)  1) Notice of References Cited (PTO-892)  2) Notice of Draftsperson's Patent Drawing Review (PTO-943)  Information Disclosure Statement(s) (PTO-1449 or PTO/5 Paper No(s)/Mail Date	Paper No	Summary (PTO-413) o(s)/Mail Date Informal Patent Application (PTO-152)					

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### **DETAILED ACTION**

### Election/Restrictions

1. Applicant's election without traverse of Group II, claims 1-19, in Paper No. 12/23/03 is acknowledged.

# Claim Rejections - 35 USC § 112

- 2. The following is a quotation of the second paragraph of 35 U.S.C. 112:
- 3. Claims 1-3 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

4. Claims 2-3 recite the limitation "the parts" in line 1. There is insufficient antecedent basis for this limitation in the claim. There are two different "the parts" in claim 1.

# Claim Rejections - 35 USC § 102

5. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

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6. Claims 1-10 and 12-16 are rejected under 35 U.S.C. 102(b) as being anticipated by Wen, US 5,812,448.

In regard to claim 1, in figs. 4a-4d, Wen discloses a method of programming memory cells, the method comprising:

depositing insulating layers 25 over parts 24 of a first portion of the cells while not depositing insulating layer over parts of second portion of the cells to thereby program the memory device; see fig. 4B.

In regard to claims 2 and 4, the parts are electrodes; see fig. 4C.

In regard to claim 3, the other parts are channels; see fig. 4C.

In regard to claims 5-7, and 12, the cells are transistors;

word lines 34 and 34' extend over the gate electrodes;

gate electrodes of the first portion are not connected to the word lines; see fig. 4D; and

gate electrodes of the second portion are connected to the word lines 34; see also fig. 4D.

In regard to claims 8, 15, Wen further discloses the insulating layers are disposed between the relative decoupling memory cells and their corresponding word lines, but are not disposed between the coupling memory cells and their word lines; see also, fig. 6.

In regard to claims 9 and 16, Wen further discloses each memory cell comprises a transistor having source/drain regions 26 a and 26b, for example, and a gate; and

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the insulating layer are disposed between the gates of the relatively decoupling memory cells and their corresponding word lines; see also, fig. 4D.

In regard to claim 10, all of the memory cells of the device should have the same substantially threshold voltage since they are uniformly formed.

In regard to claim 13, see the discussions on col. 2, lines 59-67.

In regard to claim 14, the first portion of the cells to a word line are disable by not connecting to the word lines, and a second word lines are not disable; see also fig. 4D.

## Claim Rejections - 35 USC § 103

- 7. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 8. Claim 11 is rejected under 35 U.S.C. 103(a) as being unpatentable over Wen as applied to claims 1-10 and 12-16 above, and further in view of Li et al. US 2003/0228717, hereinafter, Li.

In regard to claim 11, Wen discloses all of the claimed limitations as mentioned above accept the cells are not formed by ion-implantation. It should be noted that deposition is also a well known method of forming active regions deposition provides receiving an indication of a desired constituent ratio and calculating a deposition rate. For instance, Li discloses an analogous device using deposition to form a nonvolatile memory cells. See col. 2, section [0018].

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Therefore, it would have been obvious to one of ordinary skilled in the art at the time of the invention was made to obtain well known deposition process to form a memory device since it provides receiving an indication of a desired constituent ratio and calculating a deposition rate.

### Allowable Subject Matter

9. Claims 17-19 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Nathan W. Ha whose telephone number is (571) 272-1707. The examiner can normally be reached on M-TH 8:00-7:00(EST).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy can be reached on (571) 272-1705. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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Nathan Ha March 15, 2004

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EXAMINER

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